

6A, 200V Ultrafast Dual Diodes

The RURD620CC and RURD620CCS are ultrafast dual diodes with soft recovery characteristics ($t_{rr} < 25\text{ns}$). They have low forward voltage drop and are silicon nitride passivated ion-implanted epitaxial planar construction.

These devices are intended for use as freewheeling/clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and ultrafast soft recovery minimize ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistors.

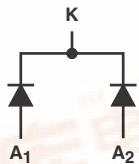
Formerly developmental type TA49037.

Ordering Information

PART NUMBER	PACKAGE	BRAND
RURD620CC	TO-251AA	UR620C
RURD620CCS	TO-252AA	UR620C

NOTE: When ordering, use the entire part number. Add the suffix, 9A, to obtain the TO-252 variant in tape and reel, i.e., RURD620CCS9A.

Symbol



Absolute Maximum Ratings (Per Leg) $T_C = 25^\circ\text{C}$ Unless Otherwise Specified

Peak Repetitive Reverse Voltage

RURD620CC
RURD620CCS

UNITS

V_{RRM}

200

V

Working Peak Reverse Voltage

V_{RWM}

200

V

DC Blocking Voltage

V_R

200

V

Average Rectified Forward Current

$I_{F(AV)}$

6

A

$T_C = 160^\circ\text{C}$

I_{FRM}

12

A

Repetitive Peak Surge Current

I_{FSM}

60

A

Square Wave, 20kHz

I_{FSM}

60

A

Nonrepetitive Peak Surge Current

I_{FSM}

60

A

Halfwave, 1 phase, 60Hz

P_D

45

W

Maximum Power Dissipation

E_{AVL}

10

mJ

Avalanche Energy (See Figures 10 and 11)

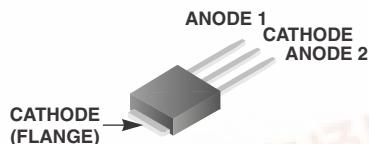
$T_{STG, TJ}$

-65 to 175

°C

Operating and Storage Temperature

JEDEC TO-251AA



JEDEC TO-252AA



RURD620CC, RURD620CCS

Electrical Specifications (Per Leg) $T_C = 25^\circ\text{C}$, Unless Otherwise Specified

SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
V_F	$I_F = 6\text{A}$	-	-	1.0	V
	$I_F = 6\text{A}, T_C = 150^\circ\text{C}$	-	-	0.83	V
I_R	$V_R = 200\text{V}$	-	-	100	μA
	$V_R = 200\text{V}, T_C = 150^\circ\text{C}$	-	-	500	μA
t_{rr}	$I_F = 1\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	-	25	ns
	$I_F = 6\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	-	30	ns
t_a	$I_F = 6\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	13	-	ns
t_b	$I_F = 6\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	6.5	-	ns
Q_{RR}	$I_F = 6\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	20	-	nC
C_J	$V_R = 10\text{V}, I_F = 0\text{A}$	-	30	-	pf
$R_{\theta\text{JC}}$		-	-	3.5	$^\circ\text{C}/\text{W}$

DEFINITIONS

V_F = Instantaneous forward voltage (pw = 300 μs , D = 2%).

I_R = Instantaneous reverse current.

t_{rr} = Reverse recovery time (See Figure 9), summation of $t_a + t_b$.

t_a = Time to reach peak reverse current (See Figure 9).

t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 9).

Q_{RR} = Reverse recovery charge.

C_J = Junction Capacitance.

$R_{\theta\text{JC}}$ = Thermal resistance junction to case.

pw = Pulse width.

D = Duty cycle.

Typical Performance Curves

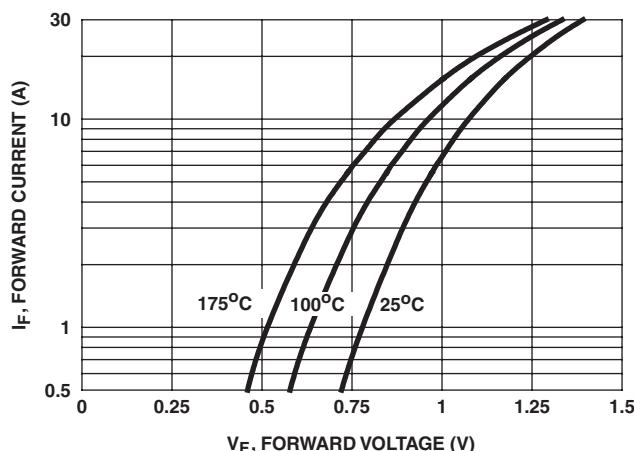


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

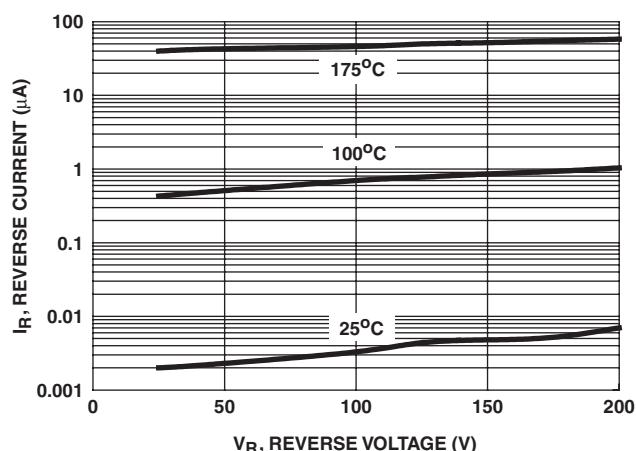


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

RURD620CC, RURD620CCS

Typical Performance Curves (Continued)

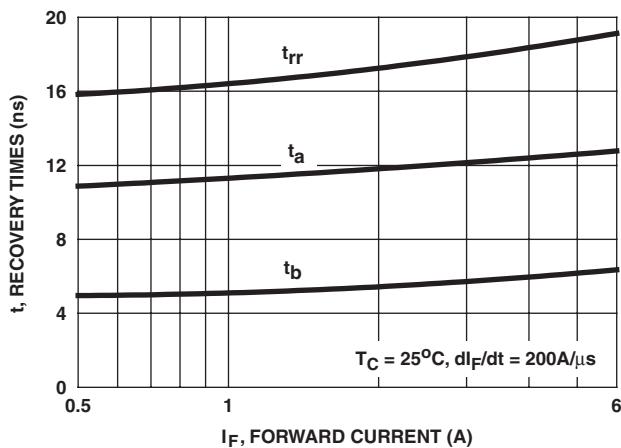


FIGURE 3. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT

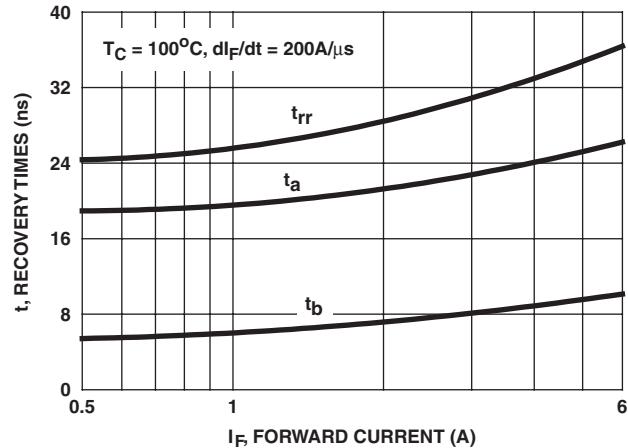


FIGURE 4. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT

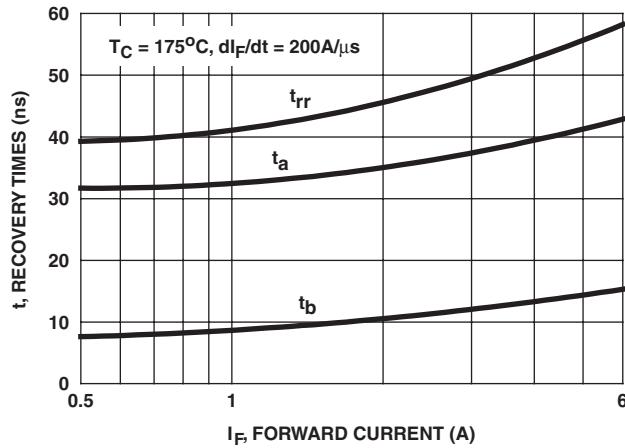


FIGURE 5. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT

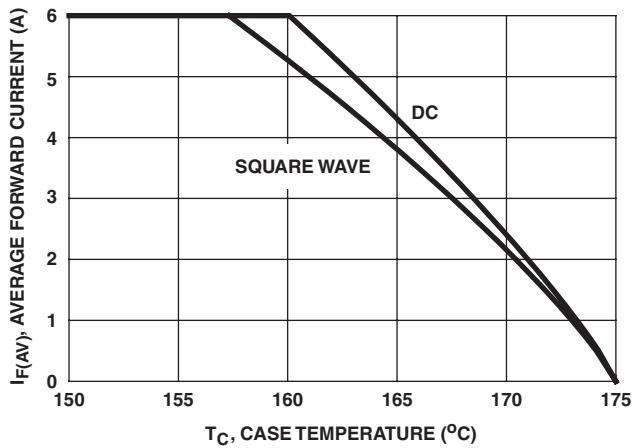


FIGURE 6. CURRENT DERATING CURVE

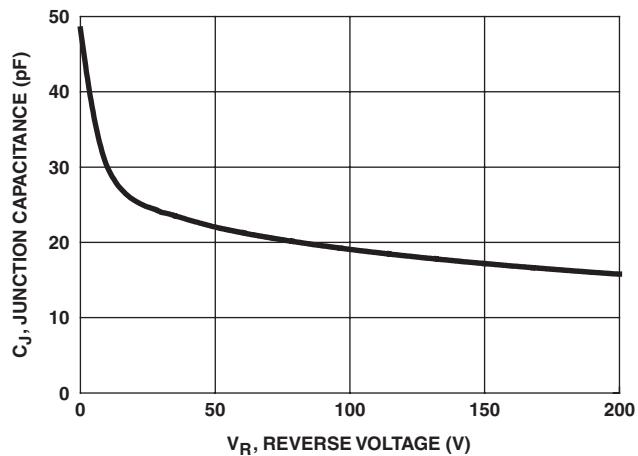


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE

Test Circuits and Waveforms

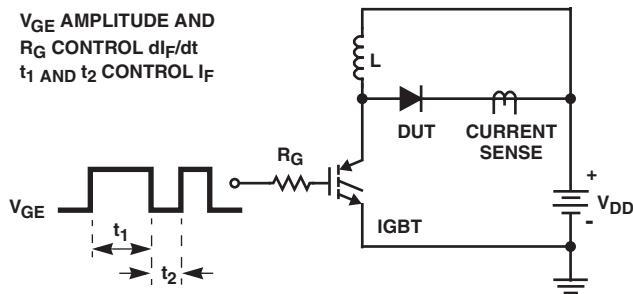


FIGURE 8. t_{rr} TEST CIRCUIT

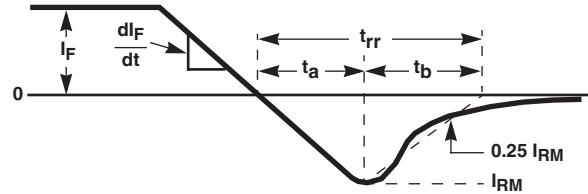


FIGURE 9. t_{rr} WAVEFORMS AND DEFINITIONS

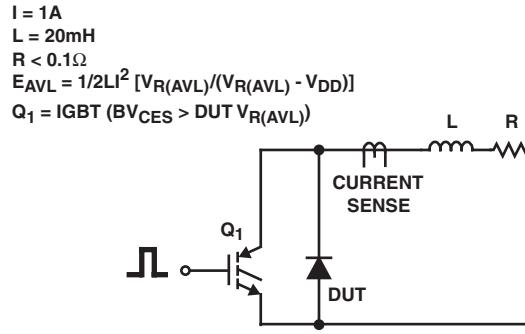


FIGURE 10. AVALANCHE ENERGY TEST CIRCUIT

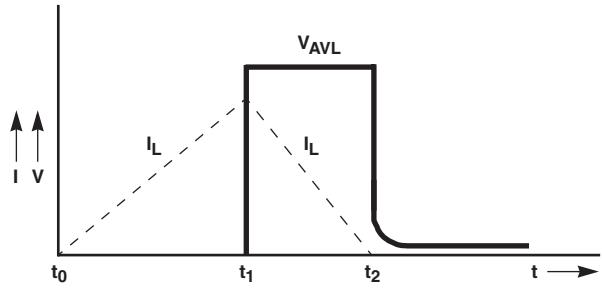


FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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